

SHINDENGEN

Schottky Rectifiers (SBD)

Single

D1FS4A

40V 1.5A

FEATURES

Small SMT
 $T_j=150^\circ C$
Low $V_F=0.45V$
 P_{RRSM} avalanche guaranteed

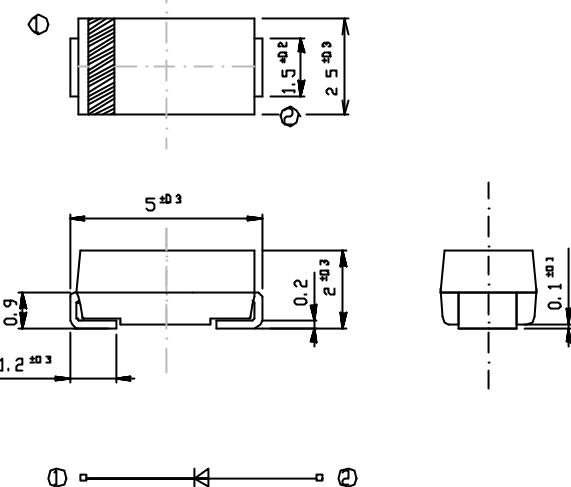
APPLICATION

Switching power supply
DC/DC converter
Home Appliances, Office Equipment
Telecommunication

OUTLINE DIMENSIONS

Case : 1F

Unit : mm



RATINGS

Absolute Maximum Ratings (If not specified $T_l=25^\circ C$)

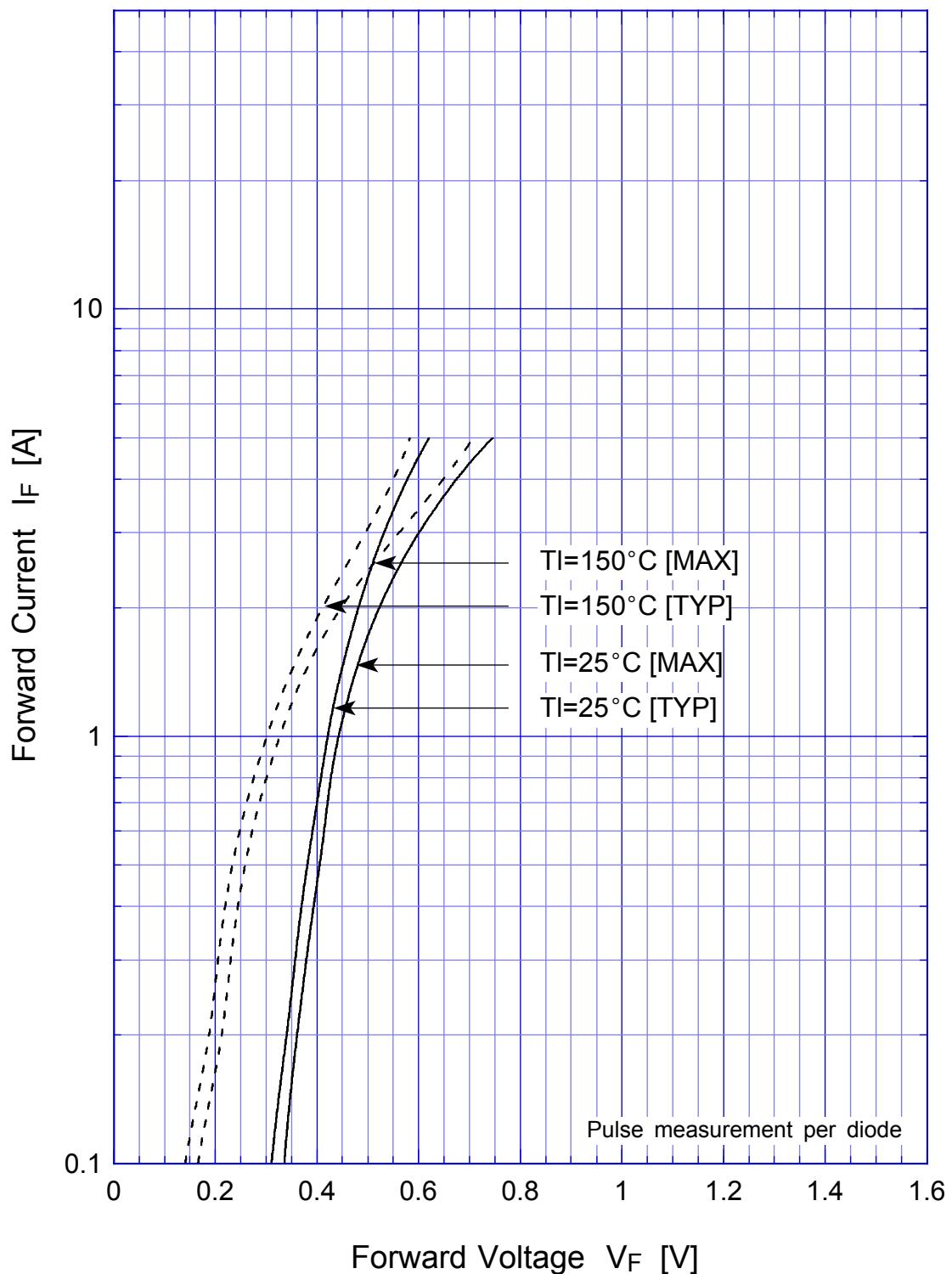
Item	Symbol	Conditions	Ratings	Unit
Storage Temperature	T_{stg}		-55 ~ 150	
Operating Junction Temperature	T_j		150	
Maximum Reverse Voltage	V_{RM}		40	V
Repetitive Peak Surge Reverse Voltage	V_{RRSM}	Pulse width 0.5ms, duty 1/40	45	V
Average Rectified Forward Current	I_o	50Hz sine wave, R-load $T_a=28^\circ C$ On alumina substrate	1.5	A
		50Hz sine wave, R-load $T_a=36^\circ C$ On glass-epoxy substrate	1.1	
Peak Surge Forward Current	I_{FSM}	50Hz sine wave, Non-repetitive 1 cycle peak value, $T_j=25^\circ C$	60	A
Repetitive Peak Surge Reverse Power	P_{RRSM}	Pulse width 10 μs , Rating of per diode, $T_j=25^\circ C$	160	W

Electrical Characteristics (If not specified $T_l=25^\circ C$)

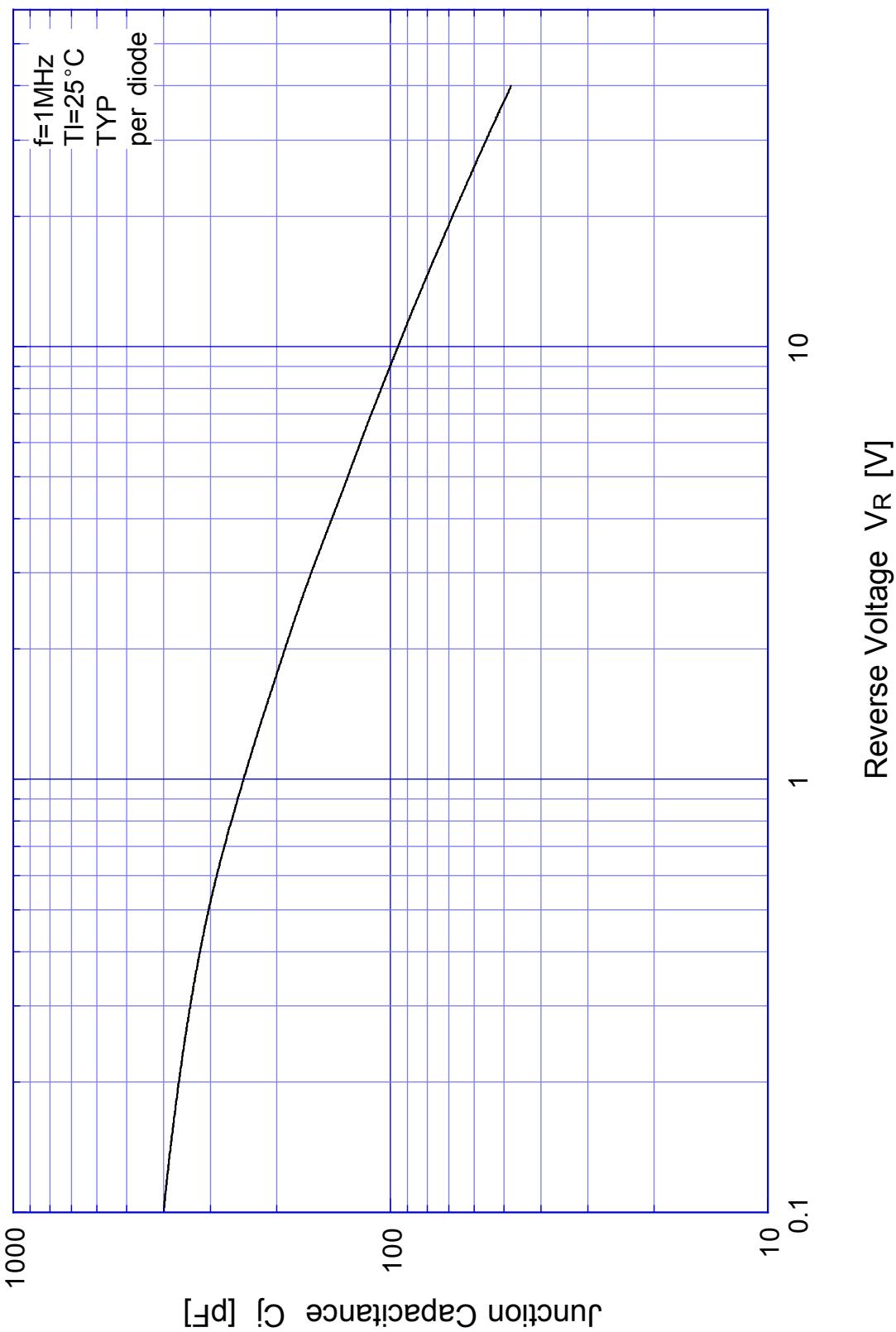
Item	Symbol	Conditions	Ratings	Unit
Forward Voltage	V_F	$I_F=1.1A$, Pulse measurement	Max.0.45	V
		$I_F=1.5A$, Pulse measurement	Max.0.48	
Reverse Current	I_R	$V_R=V_{RM}$, Pulse measurement	Max.2	mA
Junction Capacitance	C_j	$f=1MHz$, $V_R=10V$	Typ.95	pF
Thermal Resistance	j_l	junction to lead		/W
	j_a	junction to ambient On alumina substrate	Max.108	
		junction to ambient On glass-epoxy substrate	Max.157	

D1FS4A

Forward Voltage

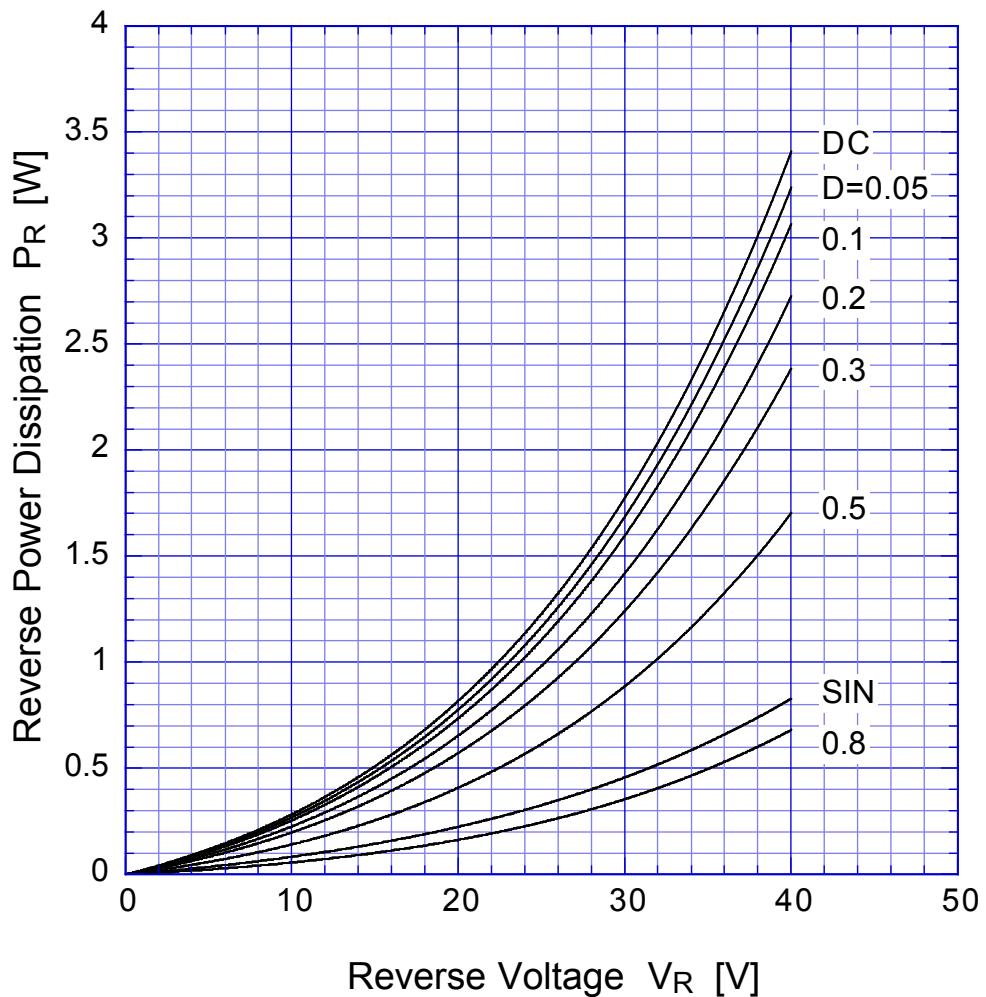


D1FS4A Junction Capacitance

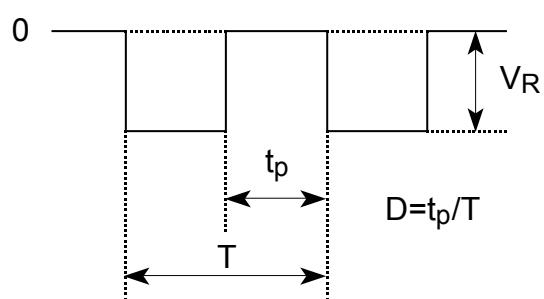


D1FS4A

Reverse Power Dissipation

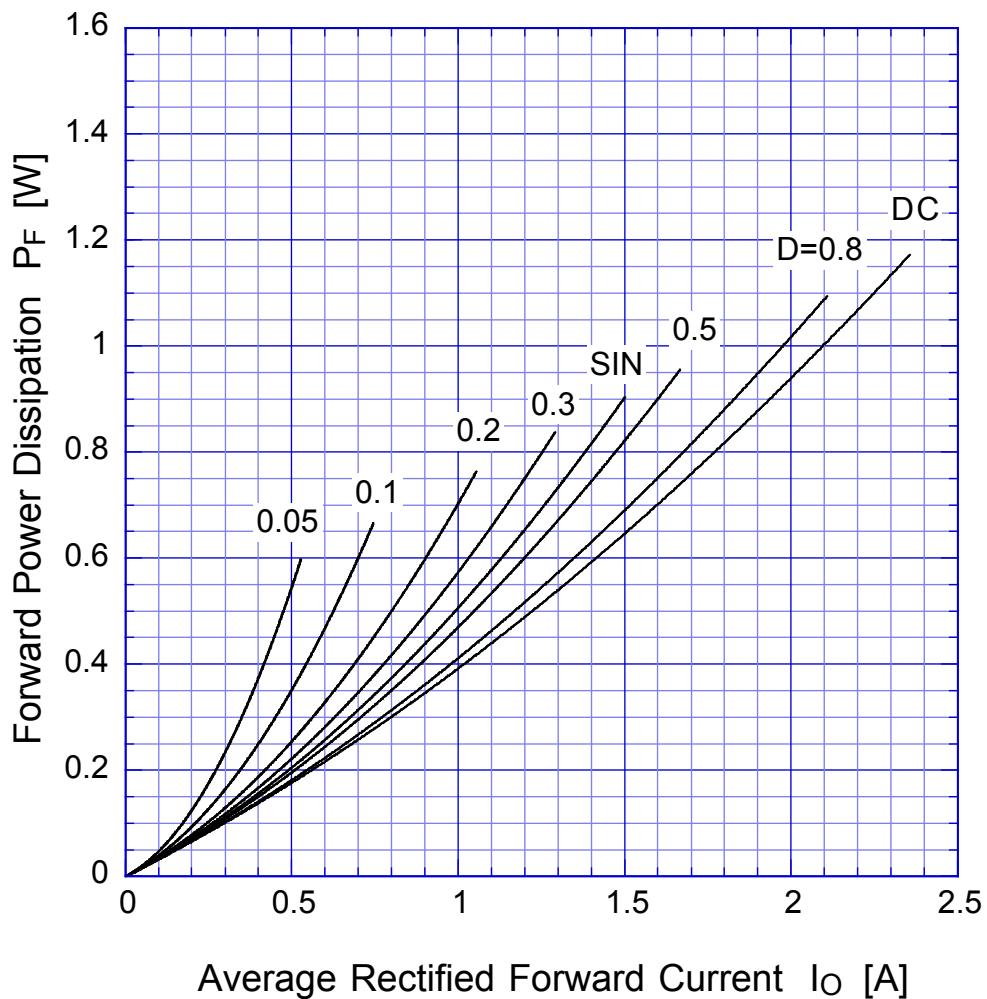


$T_j = 150^\circ\text{C}$

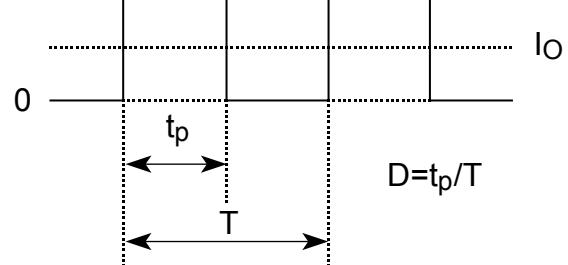


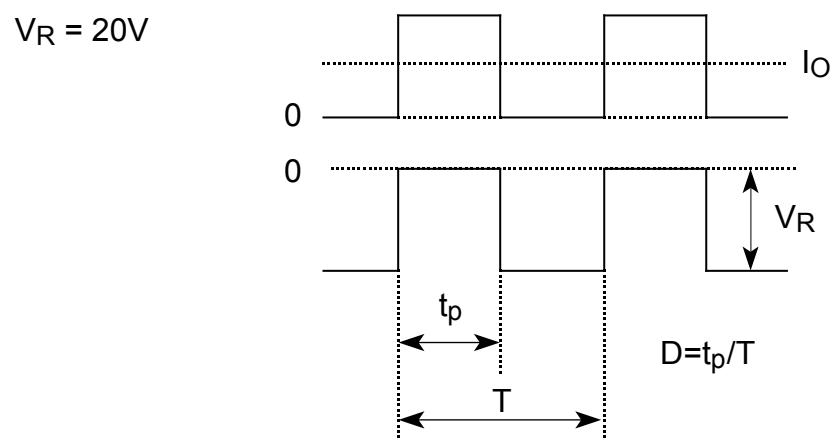
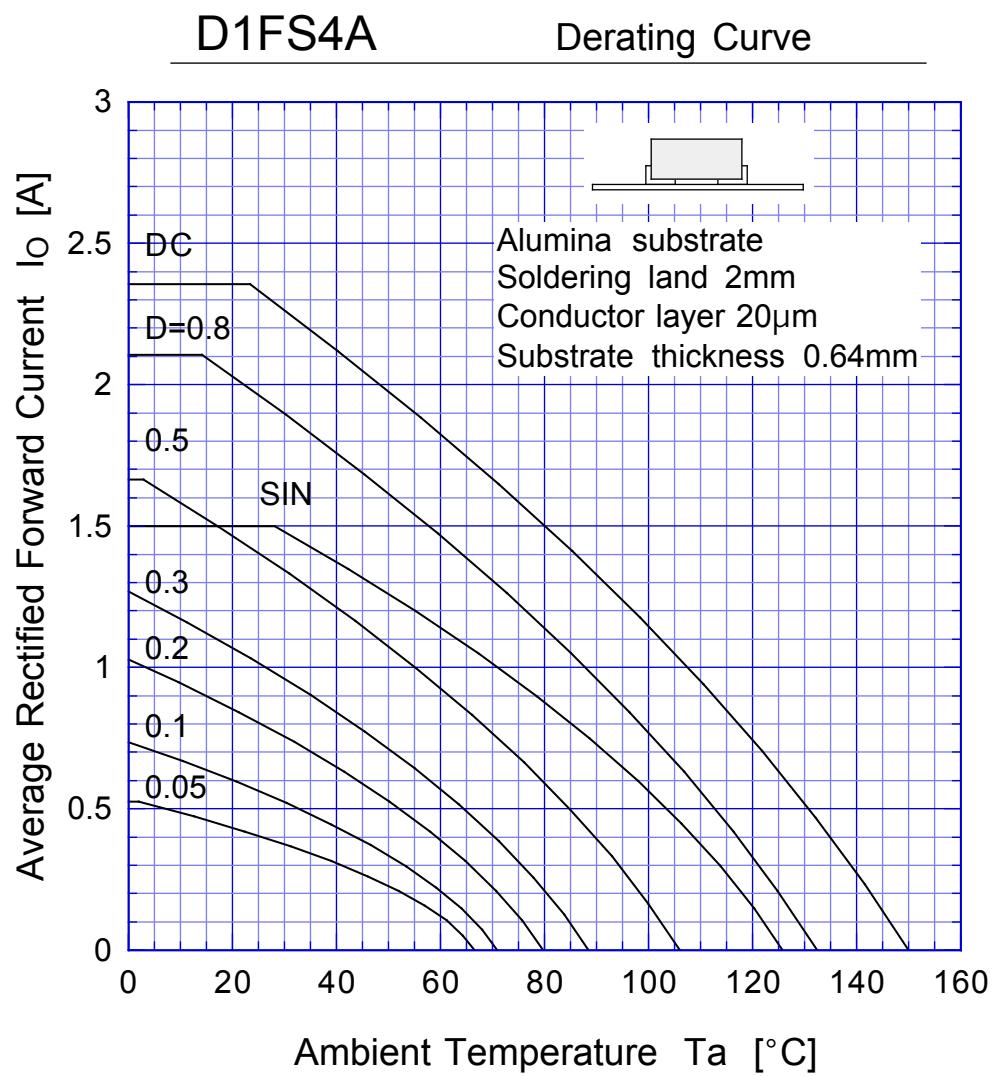
D1FS4A

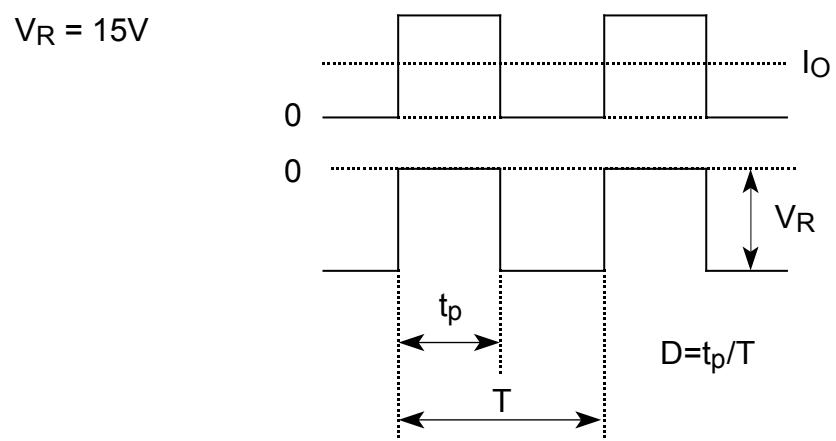
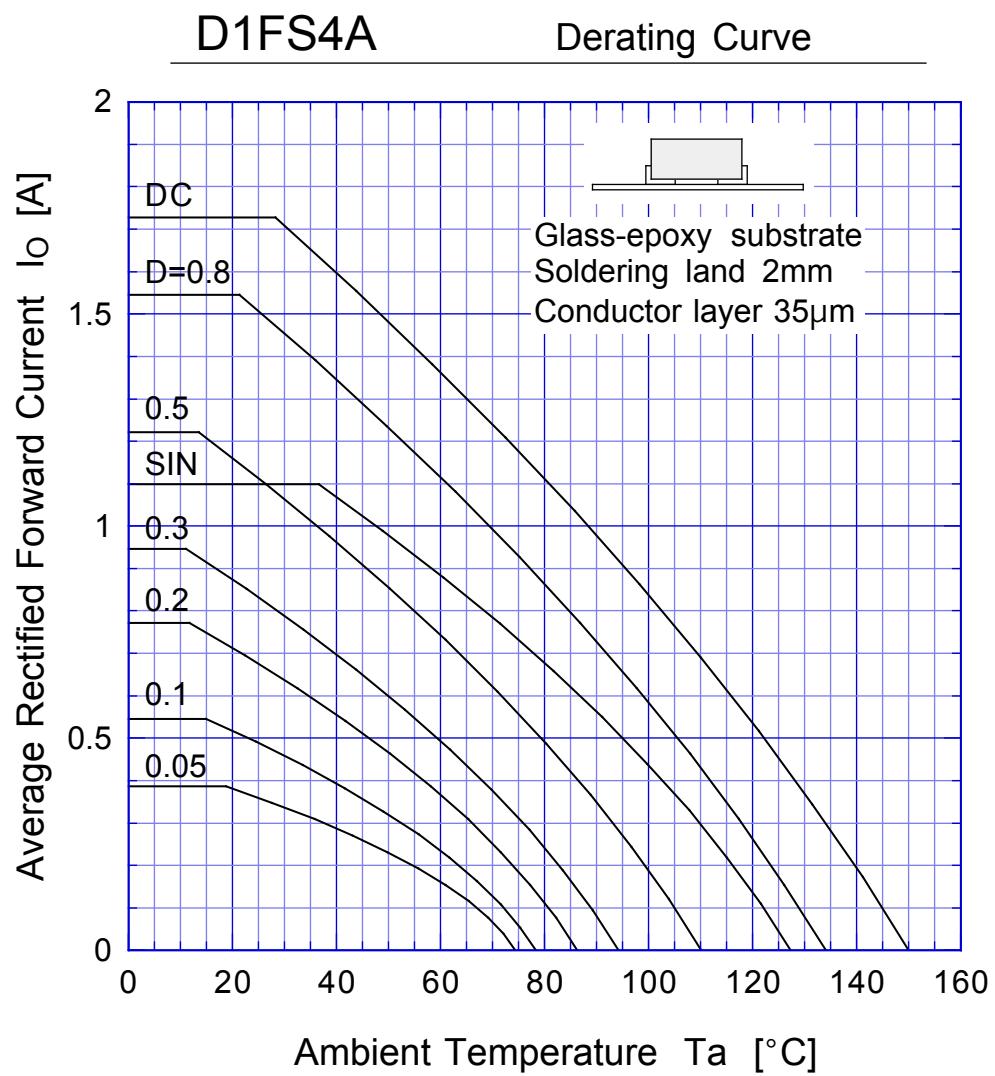
Forward Power Dissipation



$T_j = 150^\circ\text{C}$

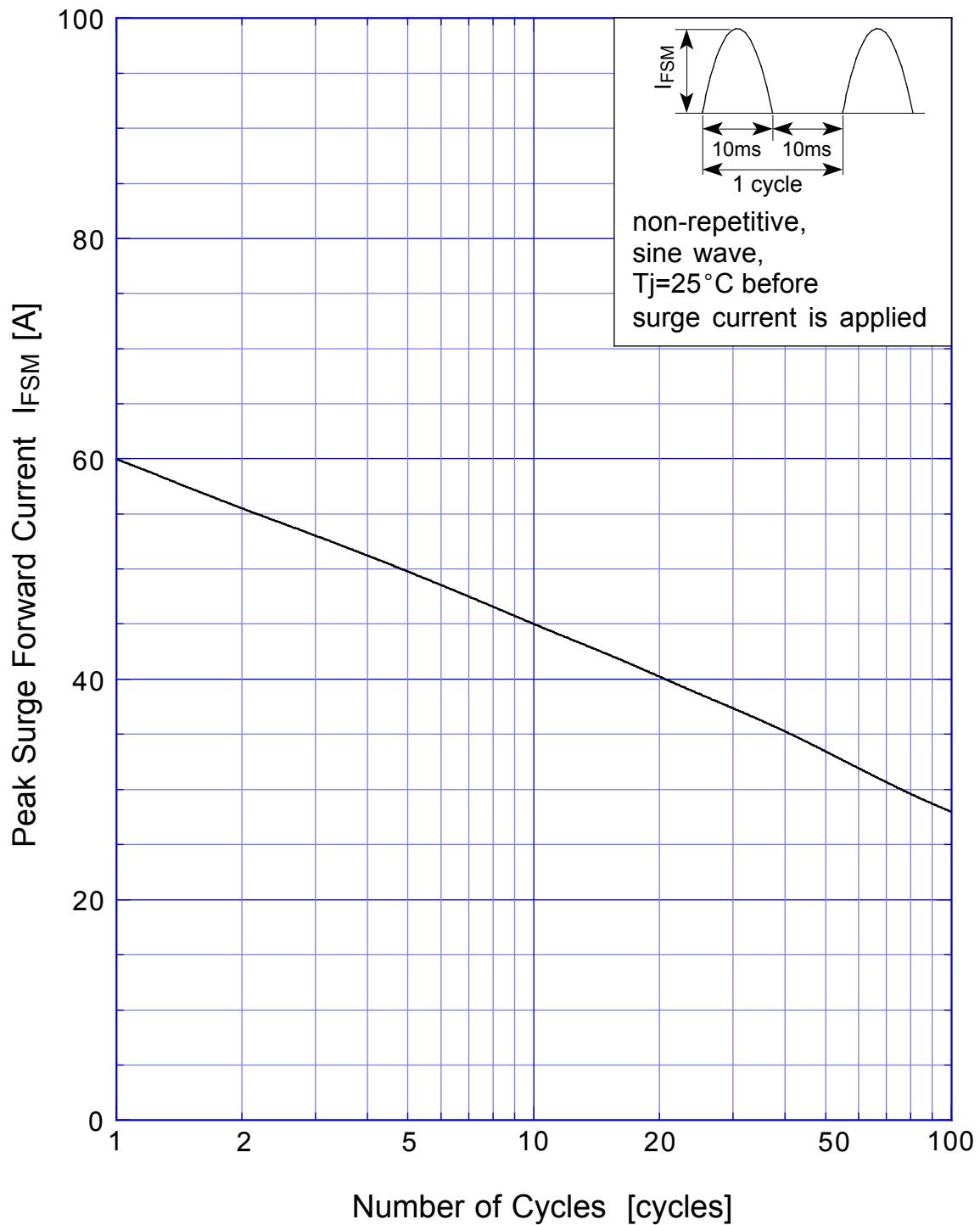






D1FS4A

Peak Surge Forward Capability



SBD Repetitive Surge Reverse Power Derating Curve



SBD Repetitive Surge Reverse Power Capability

